Dual 2-Input AND Gate

The NLX2G08 is an advanced high-speed dual 2-input CMOS AND gate in ultra-small footprint.

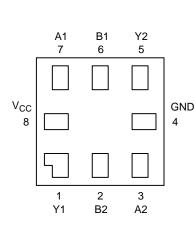
The NLX2G08 input structures provide protection when voltages up to 7.0 volts are applied, regardless of the supply voltage.

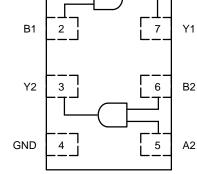
Features

- High Speed: t_{PD} 2.5 ns (typical) at $V_{CC} = 5.0$ V
- Designed for 1.65 V to 5.5 V V_{CC} Operation
- Low Power Dissipation: $I_{CC} = 1 \ \mu A$ (Max) at $T_A = 25^{\circ}C$
- 24 mA Balanced Output Sink and Source Capability
- Balanced Propagation Delays
- Overvoltage Tolerant (OVT) Input Pins
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

A1

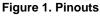
1





8

Vcc



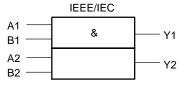


Figure 2. Logic Symbol

FUNCTION TABLE

	Y = AB		
Inp	Inputs		
Α	В	Y	
L	L	L	
L	Н	L	
н	L	L	
Н	Н	Н	
	l Logic Le Logic Lev		

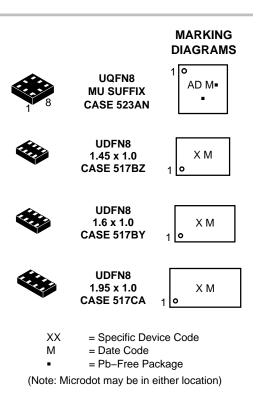
PIN ASSIGNMENT

Pin	Function (UQFN8)	Function (ULLGA/ UDFN)
1	Y1	A1
2	B2	B1
3	A2	Y2
4	GND	GND
5	Y2	A2
6	B1	B2
7	A1	Y1
8	V _{CC}	V _{CC}



ON Semiconductor®

www.onsemi.com



ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

MAXIMUM RATINGS

Symbol	Parameter		Value	Unit
V _{CC}	DC Supply Voltage		-0.5 to +7.0	V
V _{IN}	DC Input Voltage		-0.5 to +7.0	V
V _{OUT}	DC Output Voltage		-0.5 to V _{CC} + 0.5	V
Ι _{ΙΚ}	DC Input Diode Current	V _{IN} < GND	-50	mA
I _{OK}	DC Output Diode Current	-50	mA	
Ι _Ο	DC Output Source/Sink Current	±50	mA	
I _{CC}	DC Supply Current per Supply Pin		±100	mA
I _{GND}	DC Ground Current per Ground Pin		±100	mA
T _{STG}	Storage Temperature Range		-65 to +150	°C
ΤL	Lead Temperature, 1 mm from Case for 10 Secon	ds	260	°C
TJ	Junction Temperature Under Bias		+150	°C
θ_{JA}	Thermal Resistance (Note 1)		250	°C/W
PD	Power Dissipation in Still Air at 85°C		250	mW
MSL	Moisture Sensitivity		Level 1	
F _R	Flammability Rating	Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in	
V _{ESD}	ESD Withstand Voltage	Human Body Model (Note 2) Machine Model (Note 3) Charged Device Model (Note 4)	>2000 >200 N/A	V
I _{Latchup}	Latchup Performance Above V _{CC} and Below GNI	D at 125°C (Note 5)	±500	mA

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Measured with minimum pad spacing on an FR4 board, using 10 mm-by-1 inch, 2-ounce copper trace with no air flow.

2. Tested to EIA/JESD22-A114-A.

3. Tested to EIA/JESD22-A115-A.

4. Tested to JESD22–C101–A.

5. Tested to EIA/JESD78.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter		Min	Max	Unit
V _{CC}	Power DC Supply Voltage	Operating Data Retention Only	1.65 1.5	5.5 5.5	V
V _{IN}	Digital Input Voltage (Note 6)		0	5.5	V
V _{OUT}	Output Voltage		0	V _{CC}	V
T _A	Operating Free–Air Temperature		-55	+125	°C
Δt/ΔV	Input Transition Rise or Fall Rate	$V_{CC} = 1.8 V \pm 0.15 V$ $V_{CC} = 2.5 V \pm 0.2 V$ $V_{CC} = 3.3 V \pm 0.3 V$ $V_{CC} = 5.0 V \pm 0.5 V$	0 0 0 0	20 20 10 5	ns/V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

6. Unused inputs may not be left open. All inputs must be tied to a high- or low-logic input voltage level.

DC ELECTRICAL CHARACTERISTICS

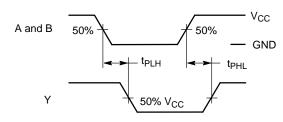
			V _{CC}	т	a = 25°	c	T _A ≤	85°C	T _A = -5 +12		
Symbol	Parameter	Condition	(V)	Min	Тур	Max	Min	Max	Min	Max	Unit
V _{IH}	High–Level Input Voltage		1.65 2.3 to 5.5	0.75 x V _{CC} 0.7 x V _{CC}			0.75 x V _{CC} 0.7 x V _{CC}		0.75 x V _{CC} 0.7 x V _{CC}		V
V _{IL}	Low–Level Input Voltage		1.65 2.3 to 5.5			0.25 x V _{CC} 0.3 x V _{CC}		0.25 x V _{CC} 0.3 x V _{CC}		0.25 x V _{CC} 0.3 x V _{CC}	V
V _{OH}	High–Level Output Voltage		1.65 to 5.5	V _{CC} – 0.1	V _{CC}		V _{CC} – 0.1		V _{CC} – 0.1		V
			1.65 2.3 2.7 3.0 3.0 4.5	1.29 1.9 2.2 2.4 2.3 3.8	1.5 2.1 2.4 2.7 2.5 4.0		1.29 1.9 2.2 2.4 2.3 3.8		1.29 1.9 2.2 2.4 2.3 3.8		
V _{OL}	Low–Level Output Voltage	$\begin{array}{l} V_{IN} = \ V_{IH} \ or \ V_{IL}, \\ I_{OL} = 100 \ \mu A \end{array}$	1.65 to 5.5			0.1		0.1		0.1	V
			1.65 2.3 2.7 3.0 3.0 4.5		0.08 0.20 0.22 0.28 0.38 0.42	0.24 0.3 0.4 0.4 0.55 0.55		0.24 0.3 0.4 0.4 0.55 0.55		0.24 0.3 0.4 0.4 0.55 0.55	
I _{IN}	Input Leakage Current	$0 \leq V_{IN} \leq 5.5 \ V$	0 to 5.5			±0.1		±1.0		±1.0	μΑ
I _{OFF}	Power–Off Input Leakage Current	V _{IN} = 5.5 V	0			1.0		10		10	μΑ
I _{CC}	Quiescent Supply Current	$0 \leq V_{IN} \leq 5.5 \text{ V}$	5.5			1.0		10		10	μΑ

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

AC ELECTRICAL CHARACTERISTICS $t_R = t_F = 2.5 \text{ ns}$

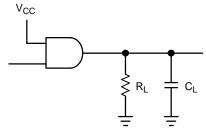
		v _{cc}		т	- A = 25°	С	T _A ≤	85°C	T _A = - to +1	-55°C 25°C	
Symbol	Parameter	(V)	Test Condition	Min	Тур	Max	Min	Max	Min	Max	Unit
t _{PLH}	Propagation Delay	1.65 to 1.95	$R_L = 1 M\Omega$, $C_L = 15 pF$	2.0	5.7	10.5	2.0	11.0	2.0	11.2	ns
t _{PHL}	Input A to Output	2.3 to 2.7	$R_L = 1 M\Omega$, $C_L = 15 pF$	1.2	3.5	5.8	1.2	6.2	1.2	6.3	
		3.0 to 3.6	$R_L = 1 M\Omega, C_L = 15 pF$	0.8	2.6	3.9	0.8	4.3	0.8	4.7	
			$R_L = 500 \ \Omega, \ C_L = 50 \ pF$		3.2	4.8		5.2		5.3	
		4.5 to 5.5	$R_L = 1 M\Omega, C_L = 15 pF$		1.9	3.1		3.3	0.5	4.0	
			$R_L = 500 \ \Omega, \ C_L = 50 \ pF$		2.5	3.7		4.0		4.3	
C _{IN}	Input Capacitance	5.5	$V_{IN} = 0 V \text{ or } V_{CC}$		2.5						pF
C _{PD}	Power Dissipation Capacitance (Note 7)	3.3 5.5	10 MHz, $V_{IN} = 0V$ or V_{CC}		9 11						pF

7. C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: $I_{CC(OPR)} = C_{PD} \bullet V_{CC} \bullet f_{in} + I_{CC}$. C_{PD} is used to determine the no–load dynamic power consumption; $P_D = C_{PD} \bullet V_{CC}^2 \bullet f_{in} + I_{CC} \bullet V_{CC}$.









A 1-MHz square input wave is recommended for propagation delay tests.

Figure 4. Test Circuit

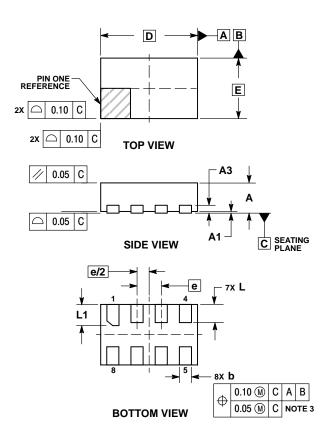
ORDERING INFORMATION

Device	Package	Shipping [†]
NLX2G08MUTCG	UQFN8 (Pb–Free)	3000 / Tape & Reel
NLX2G08DMUTCG*	UDFN8, 1.95 x 1.0, 0.5P (Pb–Free)	3000 / Tape & Reel
NLX2G08DMUTWG*	UDFN8, 1.95 x 1.0, 0.5P (Pb-Free)	3000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.
 *These device differ only in tape and reel pin 1 orientation.

PACKAGE DIMENSIONS

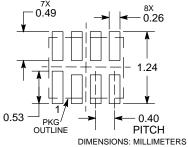
UDFN8 1.6x1.0, 0.4P CASE 517BY ISSUE O



NOTES:
 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 2. CONTROLLING DIMENSION: MILLIMETERS.
 3. DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.20 MM FROM TERMINAL TIP.
 4. PACKAGE DIMENSIONS EXCLUSIVE OF BURRS AND MOLD FLASH.

BURRS AND MOLD FI						
	MILLIN	MILLIMETERS				
DIM	MIN	MAX				
Α	0.45	0.55				
A1	0.00 0.05					
A3	0.13 REF					
b	0.15	0.25				
D	1.60	BSC				
Е	1.00	BSC				
е	0.40	BSC				
L	0.25	0.35				
L1	0.30	0.40				

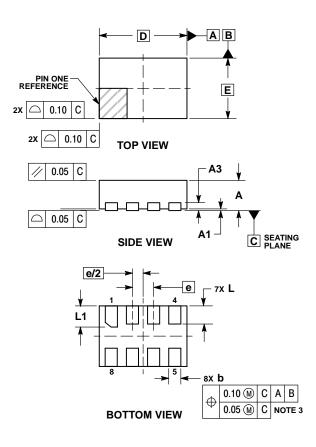
RECOMMENDED **SOLDERING FOOTPRINT***



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PACKAGE DIMENSIONS

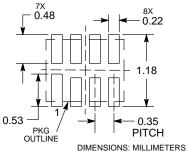
UDFN8 1.45x1.0, 0.35P CASE 517BZ ISSUE O



- NOTES:
 DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 CONTROLLING DIMENSION: MILLIMETERS.
 DIMENSION & APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.20 MM FROM TERMINAL TIP.
 PACKAGE DIMENSIONS EXCLUSIVE OF BURRS AND MOLD FLASH.

BURRS AND MOLD FL							
	MILLIN	MILLIMETERS					
DIM	MIN	MAX					
Α	0.45	0.55					
A1	0.00 0.05						
A3	0.13	REF					
b	0.15	0.25					
D	1.45	BSC					
Е	1.00	BSC					
е	0.35	BSC					
L	0.25	0.35					
L1	0.30	0.40					

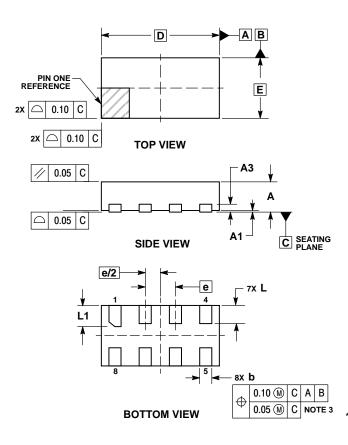
RECOMMENDED SOLDERING FOOTPRINT*



*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PACKAGE DIMENSIONS

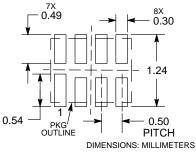
UDFN8 1.95x1.0, 0.5P CASE 517CA ISSUE O



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 2. CONTROLLING DIMENSION: MILLIMETERS.
 3. DIMENSION & APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.20 MM FROM TERMINAL TIP.
 4. PACKAGE DIMENSIONS EXCLUSIVE OF BURRS AND MOLD FLASH.

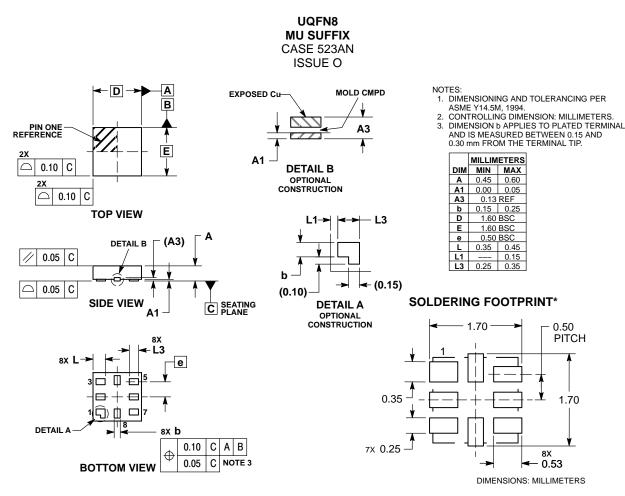
BURKS AND MOLD FI					
	MILLIN	MILLIMETERS			
DIM	MIN MAX				
Α	0.45	0.55			
A1	0.00	0.00 0.05			
A3	0.13 REF				
b	0.15	0.25			
D	1.95	BSC			
Е	1.00	BSC			
е	0.50	BSC			
L	0.25	0.35			
L1	0.30	0.40			

RECOMMENDED **SOLDERING FOOTPRINT***



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PACKAGE DIMENSIONS



*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns me rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdt/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor date sheets and/or application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights or others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that ON Semiconductor was negligent regarding the design or manufacture of the part. ON Semicon

Phone: 421 33 790 2910

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor 19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA Phone: 303–675–2175 or 800–344–3860 Toll Free USA/Canada Fax: 303–675–2176 or 800–344–3867 Toll Free USA/Canada Email: orderlit@onsemi.com N. American Technical Support: 800–282–9855 Toll Free USA/Canada Europe, Middle East and Africa Technical Support: ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

ON Semiconductor: NLX2G08MUTCG